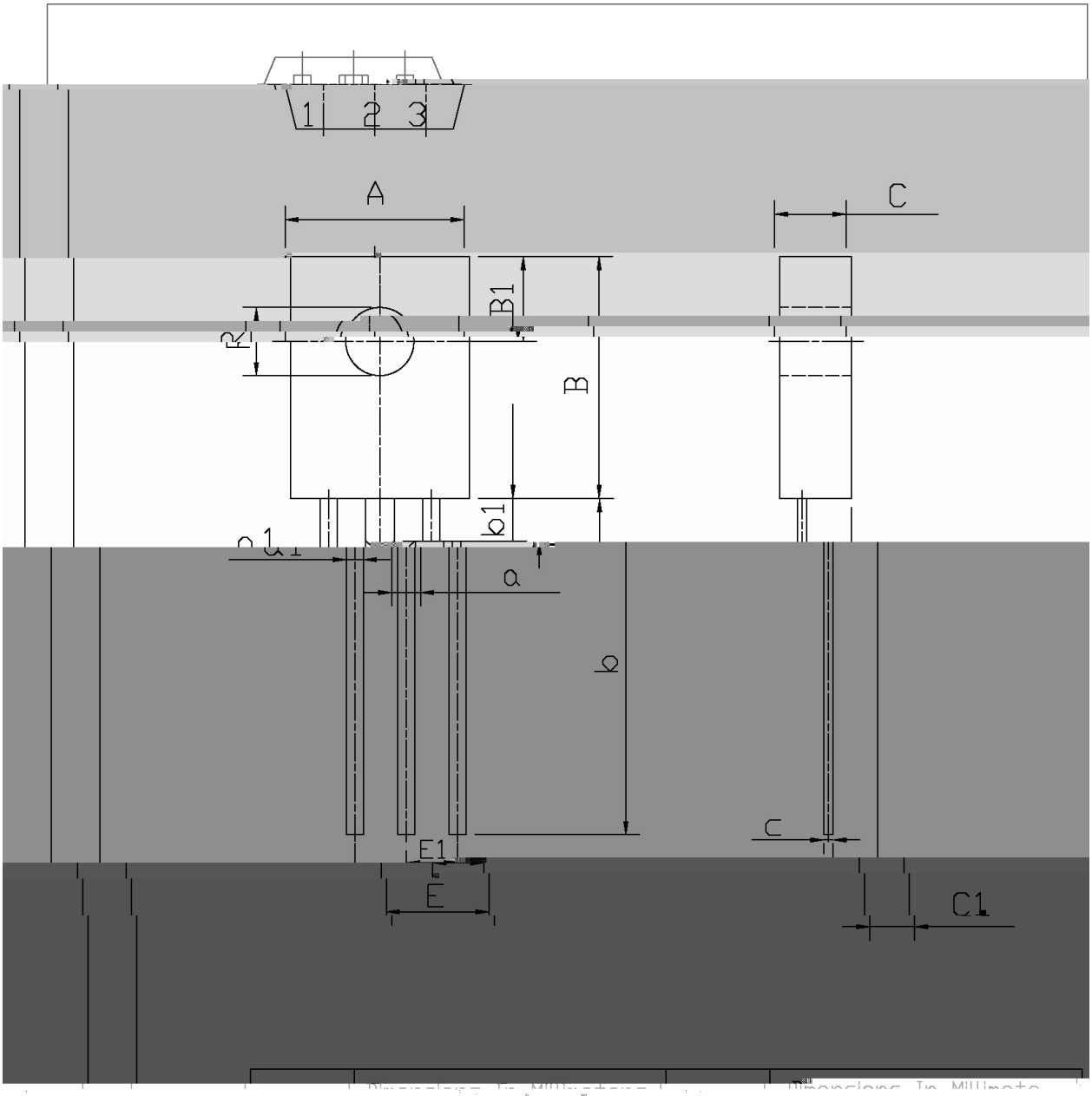
WR0459I ḾḾÞ SQS ÆṀ ч s ll ㄱ Silicon PNP transistor in a

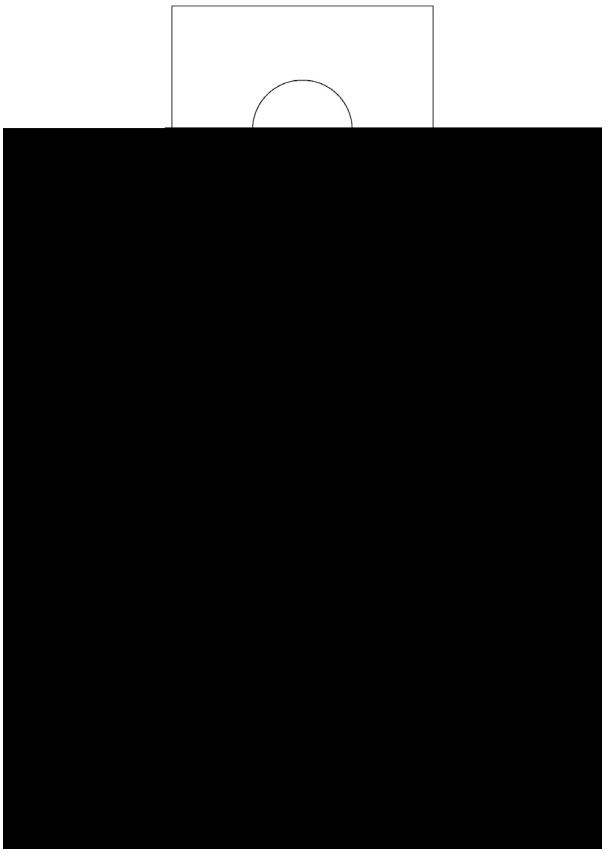
/ Package Dimensions

TO-126T 单位：mm



4.8		R	10.8	11.2	L	4.4
3.6		B1	3.8	4.2	C	3.1
2.1		R	2.95	3.15	C1	1.9
0.6		b	14	16	c	0.3
1.27		b1	1.9		a	
		E1	2.1	2.5		

/ Marking Instructions



Note:	
BR:	Company Code
BD034:	Product Type.
R	h_{FE} Classifications Symbol
****:	Lot No. Code, code change with Lot No.

( ) / Temperature Profile for Dip Soldering(Pb-Free)



ب ˝ χ

1 Ĺ ♬ □ ỷ 25 Ḱ 150 ɬ ı ˋH ڑ 60 Ḱ 90sec;

2 Š Ө □ ỷ 255 ° 5 ɬ ı ˋH ڑ ˋY ﾊ ᠷ 5 ° 0.5sec;

3 ì ˙ ϒ ˛ ɔ ଌ ỷ ᠷ 2 Ḱ 10 ɬ /sec.

Note:

1.Preheating:25~150 ɬ , Time:60~90sec.

2.Peak Temp.:255 ° 5 ɬ , Duration:5 ° 0.5sec.

3. Cooling Speed: 2~10 ɬ /sec.

/ Resistance to Soldering Heat Test Conditions

□ ỷ χ 270 ° 5 ɬ ˋH ڑ χ 10 ° 1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

ˈQ ţ ϒ Ł / BULK

Package Type	Units	Dimension (unit mm^3)